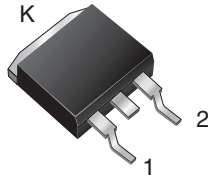
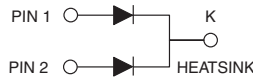


Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance

D²PAK (TO-263AB)

MBRB25HxxCT

DESIGN SUPPORT TOOLS
[click logo to get started](#)
3D
Models
Available

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
V_{RRM}	35 V, 45 V, 60 V
I_{FSM}	150 A
V_F	0.54 V, 0.60 V
I_R	100 μ A
T_J max.	175 °C
Package	D ² PAK (TO-263AB)
Circuit configuration	Common cathode

FEATURES

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA
Case: D²PAK (TO-263AB)

 Molding compound meets UL 94 V-0 flammability rating
 Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified
 ("_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)					
PARAMETER	SYMBOL	MBRB25H35CT	MBRB25H45CT	MBRB25H60CT	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	60	V
Working peak reverse voltage	V_{RWM}	35	45	60	
Maximum DC blocking voltage	V_{DC}	35	45	60	
Max. average forward rectified current (fig. 1) total device per diode	$I_{F(AV)}$	30			A
		15			
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 4$ A, $L = 10$ mH	E_{AS}	80			mJ
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150			A
Peak repetitive reverse surge current per diode at $t_p = 2.0$ μ s, 1 kHz	I_{RRM}	1.0	1.0	0.5	A
Peak non-repetitive reverse energy (8/20 μ s waveform)	E_{RSM}	25	25	20	mJ
Electrostatic discharge capacitor voltage Human body model: $C = 100$ pF, $R = 1.5$ k Ω	V_C	25			kV
Voltage rate of change (rated V_R)	dV/dt	10 000			V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +175			°C



ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MBRB25H35CT MBRB25H45CT		MBRB25H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 15 A	T _J = 25 °C	-	0.64	-	0.70	V
			T _J = 125 °C	0.50	0.54	0.56	0.60	
		I _F = 30 A	T _J = 25 °C	-	0.74	-	0.85	
			T _J = 125 °C	0.63	0.67	0.68	0.72	
Maximum reverse current per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	-	100	-	100	μA
			T _J = 125 °C	6.0	20	4.0	20	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	MBRB	UNIT
Thermal resistance, junction to case per diode	R _{θJC}	1.5	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	MBRB25H60CTHE3_B/P ⁽¹⁾	1.35	P	50/tube	Tube
TO-263AB	MBRB25H60CTHE3_B/I ⁽¹⁾	1.35	I	800/reel	Tape and reel

Note

- (1) AEC-Q101 qualified



RATINGS AND CHARACTERISTICS CURVES ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)

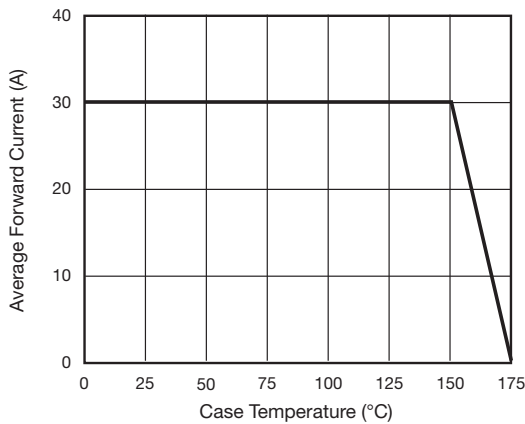


Fig. 1 - Forward Derating Curve (Total)

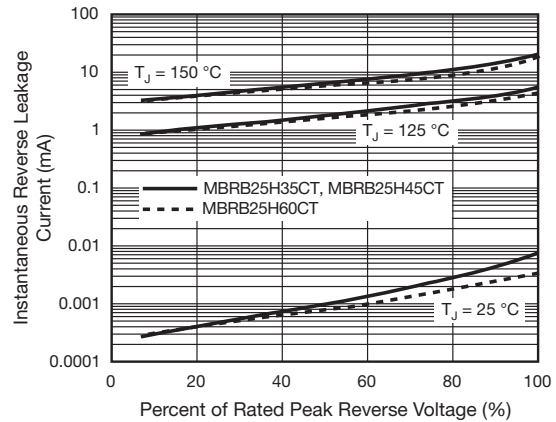


Fig. 4 - Typical Reverse Characteristics Per Diode

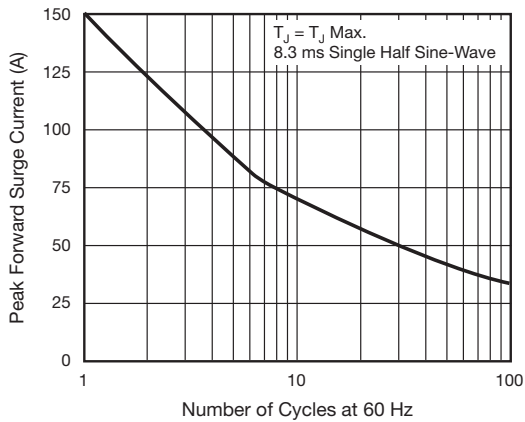


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

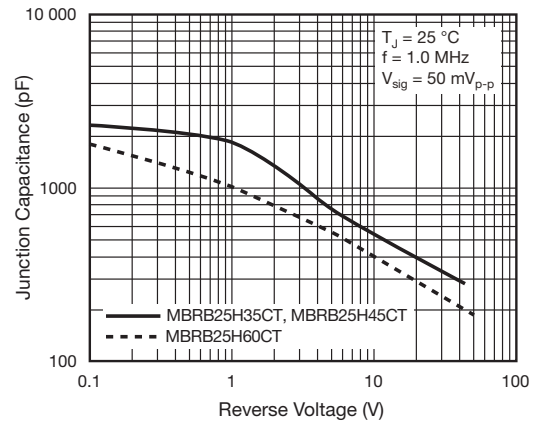


Fig. 5 - Typical Junction Capacitance Per Diode

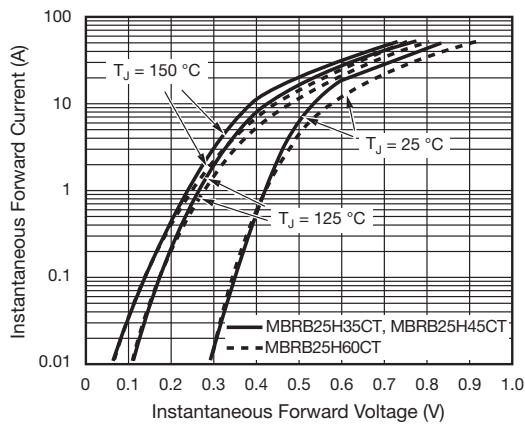


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

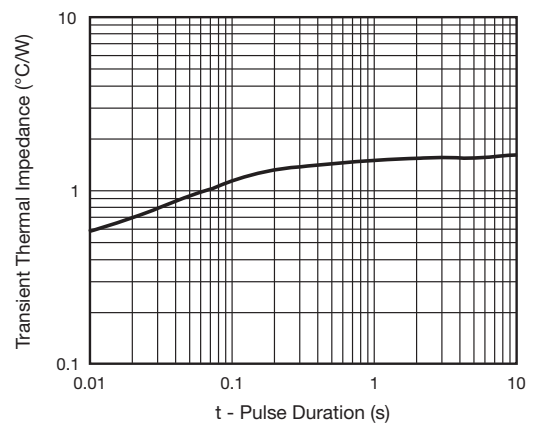
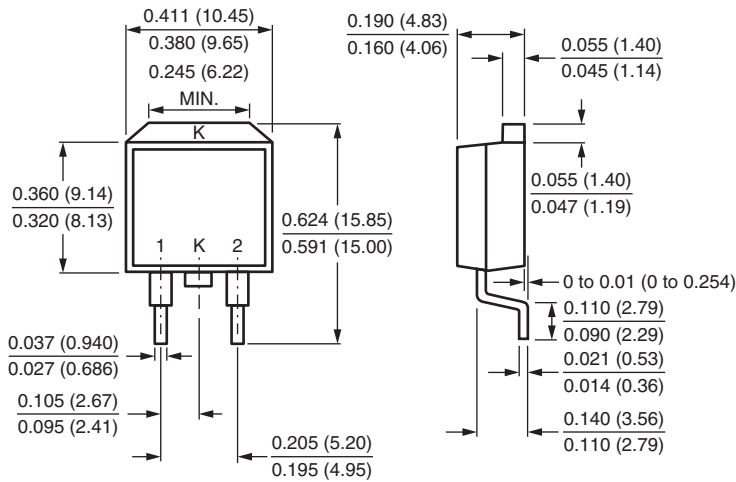


Fig. 6 - Typical Transient Thermal Impedance Per Diode

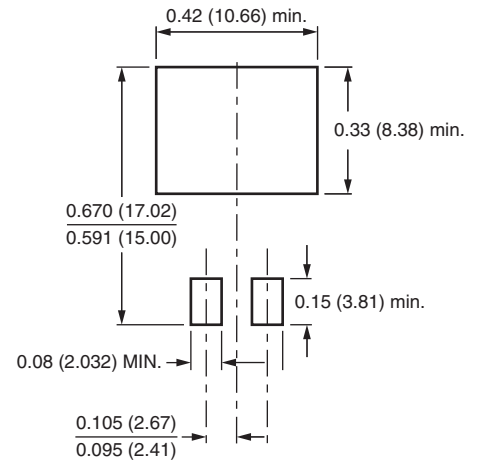


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

D²PAK (TO-263AB)



Mounting Pad Layout





Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9